

1N4678 THRU 1N4717
SILICON ZENER DIODE
LOW LEVEL
500mW, 1.8 THRU 43 VOLT
5% TOLERANCE

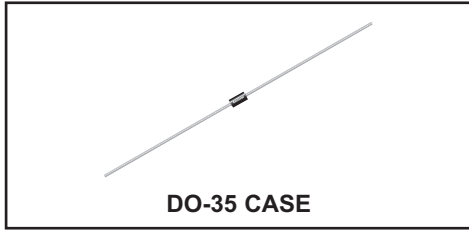


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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 1N4678 series devices are silicon Zener diodes designed for applications requiring an extremely low operating current (50µA), and low leakage.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T_L=75°C)

Power Dissipation
 Operating and Storage Junction Temperature

SYMBOL

P_D
 T_J, T_{stg}

UNITS

mW
 °C

ELECTRICAL CHARACTERISTICS: (T_A=25°C) V_F=1.5V MAX @ I_F=100mA (for all types)

| Type | Zener Voltage V _Z @ I _{ZT} | | | Test Current I _{ZT} | Maximum Reverse Leakage Current I _R @ V _R | | Maximum Voltage Change* ΔV _Z | Maximum Regulator Current I _{ZM} |
|--------|---|-----|-------|---------------------------------|--|----------------|--|--|
| | MIN | NOM | MAX | | I _R | V _R | | |
| | V | V | V | µA | µA | V | V | mA |
| 1N4678 | 1.710 | 1.8 | 1.890 | 50 | 7.5 | 1.0 | 0.70 | 120.0 |
| 1N4679 | 1.900 | 2.0 | 2.100 | 50 | 5.0 | 1.0 | 0.70 | 110.0 |
| 1N4680 | 2.090 | 2.2 | 2.310 | 50 | 4.0 | 1.0 | 0.75 | 100.0 |
| 1N4681 | 2.280 | 2.4 | 2.520 | 50 | 2.0 | 1.0 | 0.80 | 95.0 |
| 1N4682 | 2.565 | 2.7 | 2.835 | 50 | 1.0 | 1.0 | 0.85 | 90.0 |
| 1N4683 | 2.850 | 3.0 | 3.150 | 50 | 0.8 | 1.0 | 0.90 | 85.0 |
| 1N4684 | 3.135 | 3.3 | 3.465 | 50 | 7.5 | 1.5 | 0.95 | 80.0 |
| 1N4685 | 3.420 | 3.6 | 3.780 | 50 | 7.5 | 2.0 | 0.95 | 75.0 |
| 1N4686 | 3.705 | 3.9 | 4.095 | 50 | 5.0 | 2.0 | 0.97 | 70.0 |
| 1N4687 | 4.085 | 4.3 | 4.515 | 50 | 4.0 | 2.0 | 0.99 | 65.0 |
| 1N4688 | 4.465 | 4.7 | 4.935 | 50 | 10 | 3.0 | 0.99 | 60.0 |
| 1N4689 | 4.845 | 5.1 | 5.355 | 50 | 10 | 3.0 | 0.97 | 55.0 |
| 1N4690 | 5.320 | 5.6 | 5.880 | 50 | 10 | 4.0 | 0.96 | 50.0 |
| 1N4691 | 5.890 | 6.2 | 6.510 | 50 | 10 | 5.0 | 0.95 | 45.0 |
| 1N4692 | 6.460 | 6.8 | 7.140 | 50 | 10 | 5.1 | 0.90 | 35.0 |
| 1N4693 | 7.125 | 7.5 | 7.875 | 50 | 10 | 5.7 | 0.75 | 31.8 |
| 1N4694 | 7.790 | 8.2 | 8.610 | 50 | 1.0 | 6.2 | 0.50 | 29.0 |
| 1N4695 | 8.265 | 8.7 | 9.135 | 50 | 1.0 | 6.6 | 0.10 | 27.6 |
| 1N4696 | 8.645 | 9.1 | 9.555 | 50 | 1.0 | 6.9 | 0.08 | 26.2 |
| 1N4697 | 9.500 | 10 | 10.50 | 50 | 1.0 | 7.6 | 0.10 | 24.8 |

* ΔV_Z=V_Z @ 100µA Minus V_Z @ 10µA

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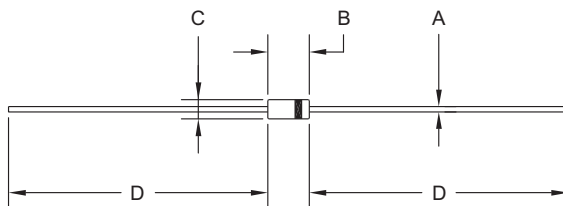


ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^{\circ}\text{C}$) $V_F=1.5\text{V MAX @ } I_F=100\text{mA}$ (for all types)

| Type | Zener Voltage $V_Z @ I_{ZT}$ | | | Test Current I_{ZT} | Maximum Reverse Leakage Current $I_R @ V_R$ | | Maximum Voltage Change* ΔV_Z | Maximum Regulator Current I_{ZM} |
|--------|---------------------------------|-----|-------|--------------------------|--|------------|---|---------------------------------------|
| | MIN | NOM | MAX | | μA | V | | |
| | V | V | V | μA | V | V | mA | |
| 1N4698 | 10.45 | 11 | 11.55 | 50 | 0.05 | 8.4 | 0.11 | 21.6 |
| 1N4699 | 11.40 | 12 | 12.60 | 50 | 0.05 | 9.1 | 0.12 | 20.4 |
| 1N4700 | 12.35 | 13 | 13.65 | 50 | 0.05 | 9.8 | 0.13 | 19.0 |
| 1N4701 | 13.30 | 14 | 14.70 | 50 | 0.05 | 10.6 | 0.14 | 17.5 |
| 1N4702 | 14.25 | 15 | 15.75 | 50 | 0.05 | 11.4 | 0.15 | 16.3 |
| 1N4703 | 15.20 | 16 | 16.80 | 50 | 0.05 | 12.1 | 0.16 | 15.4 |
| 1N4704 | 16.15 | 17 | 17.85 | 50 | 0.05 | 12.9 | 0.17 | 14.5 |
| 1N4705 | 17.10 | 18 | 18.90 | 50 | 0.05 | 13.6 | 0.18 | 13.2 |
| 1N4706 | 18.05 | 19 | 19.95 | 50 | 0.05 | 14.4 | 0.19 | 12.5 |
| 1N4707 | 19.00 | 20 | 21.00 | 50 | 0.01 | 15.2 | 0.20 | 11.9 |
| 1N4708 | 20.90 | 22 | 23.10 | 50 | 0.01 | 16.7 | 0.22 | 10.8 |
| 1N4709 | 22.80 | 24 | 25.20 | 50 | 0.01 | 18.2 | 0.24 | 9.9 |
| 1N4710 | 23.75 | 25 | 26.25 | 50 | 0.01 | 19.0 | 0.25 | 9.5 |
| 1N4711 | 25.65 | 27 | 28.35 | 50 | 0.01 | 20.4 | 0.27 | 8.8 |
| 1N4712 | 26.60 | 28 | 29.40 | 50 | 0.01 | 21.2 | 0.28 | 8.5 |
| 1N4713 | 28.50 | 30 | 31.50 | 50 | 0.01 | 22.8 | 0.30 | 7.9 |
| 1N4714 | 31.35 | 33 | 34.65 | 50 | 0.01 | 25.0 | 0.33 | 7.2 |
| 1N4715 | 34.20 | 36 | 37.80 | 50 | 0.01 | 27.3 | 0.36 | 6.6 |
| 1N4716 | 37.05 | 39 | 40.95 | 50 | 0.01 | 29.6 | 0.39 | 6.1 |
| 1N4717 | 40.85 | 43 | 45.15 | 50 | 0.01 | 32.6 | 0.43 | 5.5 |

* $\Delta V_Z = V_Z @ 100\mu\text{A}$ Minus $V_Z @ 10\mu\text{A}$

DO-35 CASE - MECHANICAL OUTLINE



| SYMBOL | DIMENSIONS | | DIMENSIONS | |
|--------|------------|-------|-------------|------|
| | INCHES | | MILLIMETERS | |
| | MIN | MAX | MIN | MAX |
| A | 0.018 | 0.022 | 0.46 | 0.56 |
| B | 0.120 | 0.200 | 3.05 | 5.08 |
| C | 0.060 | 0.090 | 1.52 | 2.29 |
| D | 1.000 | - | 25.40 | - |

DO-35 (REV: R1)

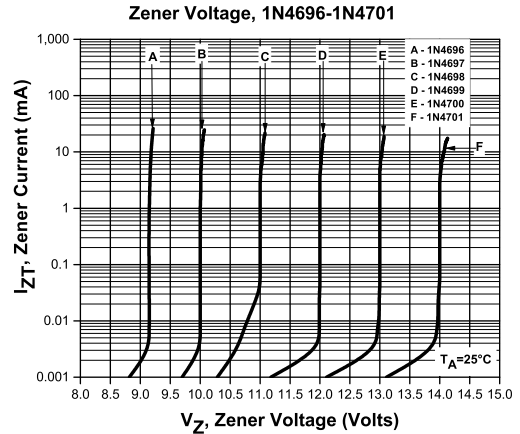
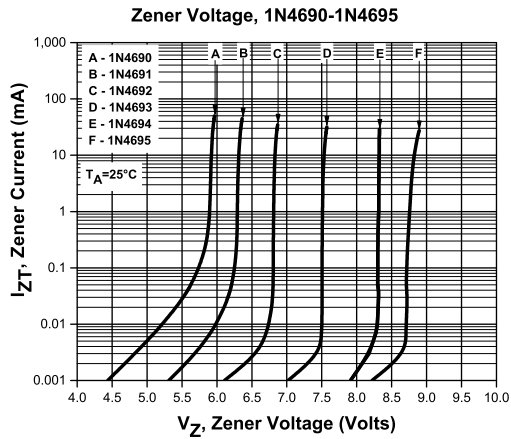
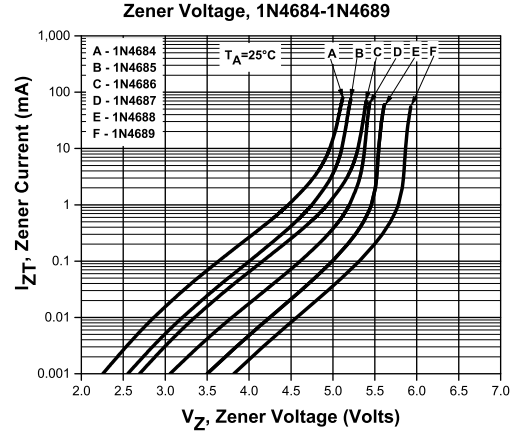
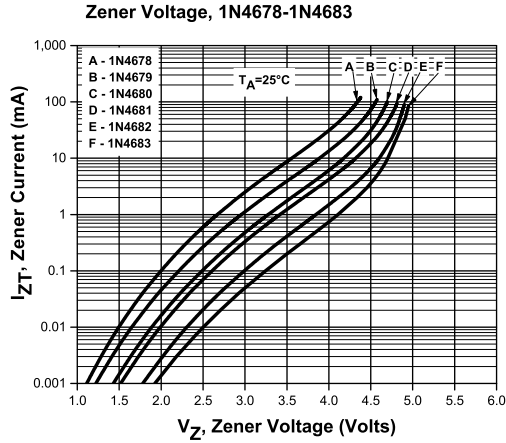
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R5 (8-October 2015)

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TYPICAL ELECTRICAL CHARACTERISTICS

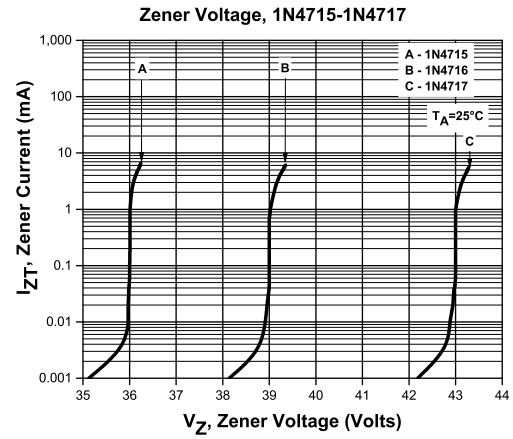
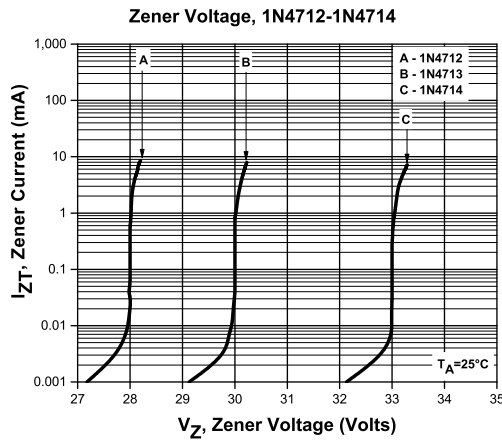
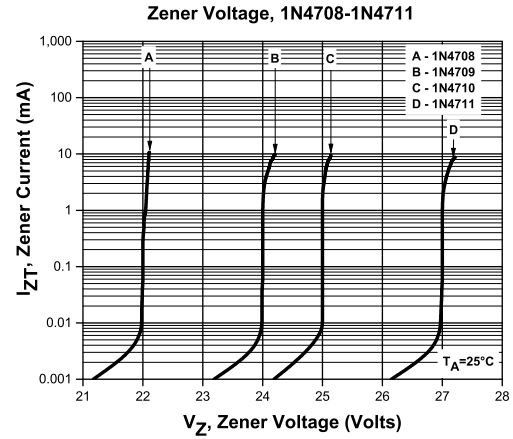
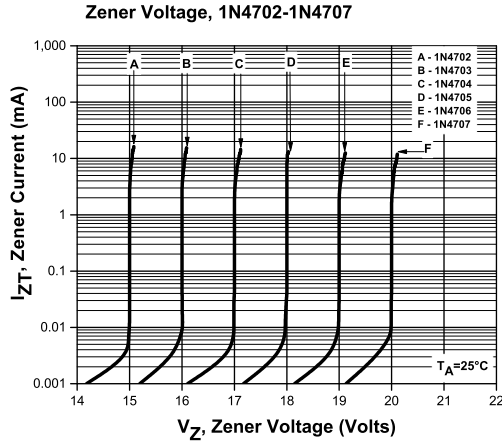


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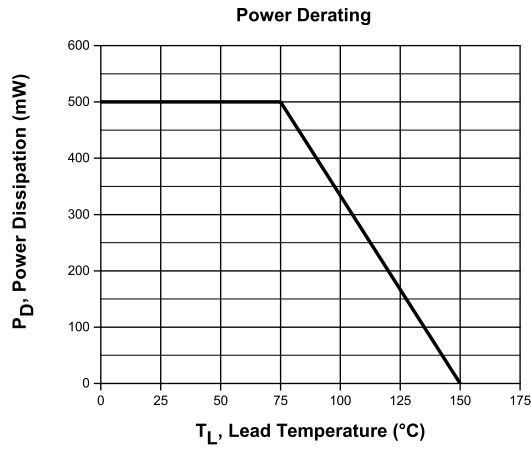


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TYPICAL ELECTRICAL CHARACTERISTICS



R5 (8-October 2015)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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